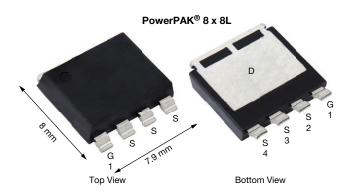


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Vishay Siliconix

Automotive N-Channel 40 V (D-S) 175 °C MOSFET

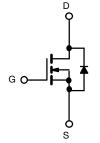


PRODUCT SUMMARY	
V _{DS} (V)	40
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0007
I _D (A) ^e	487
Configuration	Single

FEATURES

- TrenchFET® Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Thin 1.6 mm package
- · Very low thermal resistance
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





N-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK 8 x 8L
Lead (Pb)-free and halogen-free	SQJQ146E (for detailed order number please see www.vishay.com/doc?79776)

ABSOLUTE MAXIMUM RATIN	GS ($T_C = 25$ °C, unles	s otherwise noted	l)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V_{DS}	40		
Gate-source voltage		V_{GS}	± 20	V	
Continuous drain current ^e	T _C = 25 °C	1	487		
	T _C = 125 °C	· I _D	281		
Continuous source current (diode conduction) e		I _S	272	А	
Pulsed drain current a, e		I _{DM}	1166		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	70		
Single pulse avalanche energy	L = 0.1 MH	E _{AS}	245	mJ	
Maximum power dissipation ^e	T _C = 25 °C	Ъ	300	14/	
	T _C = 125 °C	P_{D}	100	W	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°0	
Soldering recommendations (peak temperature) c			260	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount c	R_{thJA}	44	°C/W	
Junction-to-case (drain) ^d	se (drain) ^d		0.5	G/ VV	

Notes

- a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %
- b. When mounted on 1" square PCB (FR4 material)
- c. See solder profile (www.vishay.com/doc?73257). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- d. As per JESD51-14
- e. Values based on R_{thJC} and T_C of 25 °C. Actual values achievable will be dependent on the thermal characteristics of the complete system



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static					•			
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0$, $I_D = 250 \mu A$		40	-	-	V	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA		2.2	2.8	3.2	V	
Gate-source leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	-	± 100	nA	
Zero gate voltage drain current		$V_{GS} = 0 V$	V _{DS} = 40 V	-	-	1		
	I _{DSS}	V _{GS} = 0 V	V _{DS} = 40 V, T _J = 125 °C	-	-	200	μΑ	
		V _{GS} = 0 V	V _{DS} = 40 V, T _J = 175 °C	-	-	800		
On-state drain current a	I _{D(on)}	V _{GS} = 10 V	V _{DS} ≥ 5 V	100	-	-	Α	
Drain-source on-state resistance ^a		V _{GS} = 10 V	I _D = 20 A	-	0.00055	0.0007	Ω	
	R _{DS(on)}	V _{GS} = 10 V	I _D = 20 A, T _J = 125 °C	-	-	0.00105		
		V _{GS} = 10 V	I _D = 20 A, T _J = 175 °C	-	-	0.00128		
Forward transconductance b	9 _{fs}	V _{DS} = 15 V, I _D = 100 A		-	310	-	S	
Dynamic ^b								
Input capacitance	C _{iss}		V _{DS} = 25 V, f = 1 MHz	-	10 038	14 054	pF	
Output capacitance	C _{oss}	$V_{GS} = 0 V$		-	3014	4220		
Reverse transfer capacitance	C _{rss}			-	219	307		
Total gate charge ^c	Qg			-	159	239		
Gate-source charge c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 20 \text{ V}, I_{D} = 40 \text{ A}$	-	49	-	nC	
Gate-drain charge c	Q_{gd}			-	33	-		
Gate resistance	R_g	f = 1 MHz		0.6	1.6	3.2	Ω	
Turn-on delay time ^c	t _{d(on)}			-	21	32		
Rise time ^c	t _r	$V_{DD} = 20 \text{ V}, \text{ R}_{L} = 0.5 \Omega$ $I_{D} \cong 40 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_{g} = 1 \Omega$		-	18	27	ns	
Turn-off delay time ^c	t _{d(off)}			-	55	83		
Fall time ^c	t _f			-	22	33		
Source-Drain Diode Ratings and Cha	aracteristics ^b							
Reverse recovery time	t _{rr}	V _{DD} = 32 V, I _{FM} = 40 A, di/dt = 100 A/μs		-	75	150	ns	
Reverse recovery charge	Q _{rr}			-	107	214	nC	
Reverse recovery current	I _{RM}			-	-2.6	_	Α	
Pulsed current ^a	I _{SM}			-	-	719	Α	
Forward voltage	V_{SD}	$I_F = 50 \text{ A}, V_{GS} = 0$		_	0.8	1.1	V	

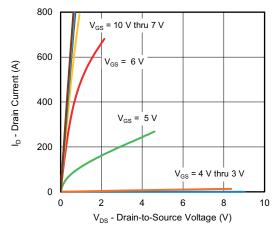
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

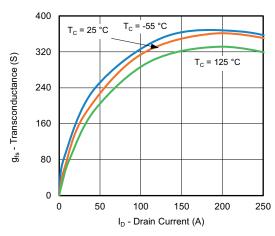
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



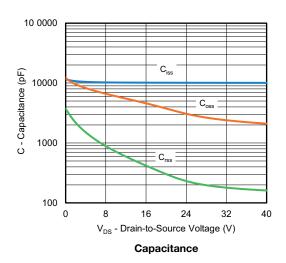
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

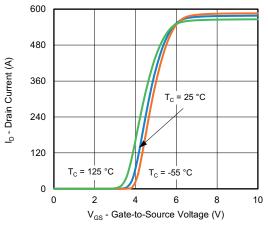


Output Characteristics

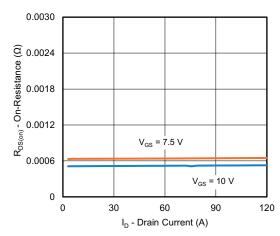


Transconductance

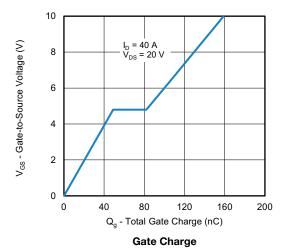




Transfer Characteristics

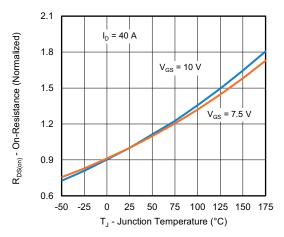


On-Resistance vs. Drain Current

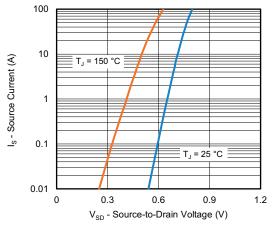




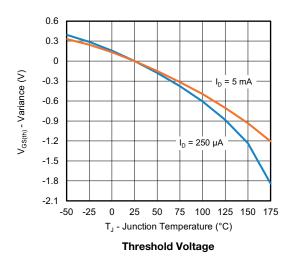
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

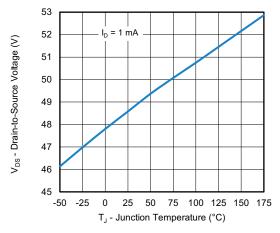


On-Resistance vs. Junction Temperature

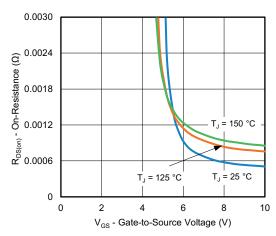


Source Drain Diode Forward Voltage

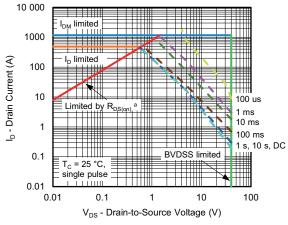




Drain Source Breakdown vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage



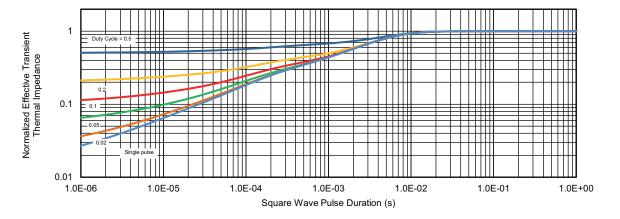
Safe Operating Area

Note

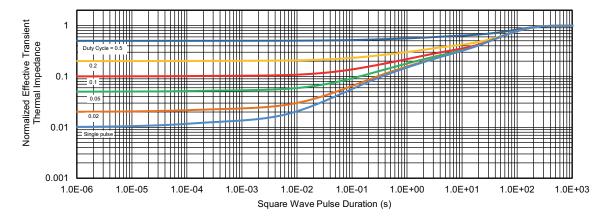
a. $V_{GS} > minimum V_{GS}$ at which $R_{DS(on)}$ is specified



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient

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